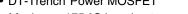


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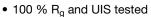
N-Channel 150 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A)	Q _g (TYP.)			
150	0.0076 at V _{GS} = 10 V	110	63 nC			
150	0.0081 at V _{GS} = 7.5 V	100	63 110			











APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- Solar micro inverter
- Class D audio amplifier
- · Battery management



ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V _{DS}	150	V			
Gate-Source Voltage	V _{GS}	± 20	V			
Continuous Drain Current (T, I = 150 °C)	T _C = 25 °C	1-	110			
Continuous Drain Current (1) = 150 C)	T _C = 125 °C	l _D	74			
Pulsed Drain Current (t = 100 μs)		I _{DM}	330	А		
Avalanche Current	L = 0.1 mH	I _{AS}	60			
Single Avalanche Energy ^a	L = U.T MIH	E _{AS}	180	mJ		
Maximum Power Dissipation ^a	T _C = 25 °C	В	375 ^b	W		
Maximum Fower Dissipation 4	T _C = 125 °C	$ P_D$	125 ^b	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		
Operating Junction and Storage Temperature I	Range	T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C // /		
Junction-to-Case (Drain)	R _{thJC}	0.4	°C/W		

Notes

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.
- c. When mounted on 1" square PCB (FR4 material).



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	150	-	-	- 5
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	5	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		V _{DS} = 150 V, V _{GS} = 0 V	-	-	1	^
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V, T _J = 125 °C	-	-	100	μA
		V _{DS} = 150 V, V _{GS} = 0 V, T _J = 175 °C	-	-	2	mA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	90	-	-	Α
Drain Course On Ctata Desistance C	Б	V _{GS} = 10 V, I _D = 20 A	-	0.0076	0.0084	0
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 7.5 \text{ V}, I_D = 10 \text{ A}$	-	0.0081	0.0089	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 10 A	-	52	-	S
Dynamic ^b						
Input Capacitance	C _{iss}		-	4225	-	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 75 V, f = 1 MHz	-	535	-	
Reverse Transfer Capacitance	C _{rss}		-	26	-	
Total Gate Charge ^c	Qg		-	63	95	nC
Gate-Source Charge ^c	Q_{gs}	$V_{DS} = 75 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$	-	19.5	-	
Gate-Drain Charge ^c	Q _{gd}		-	20.5	-	
Gate Resistance	R_g	f = 1 MHz	1.5	3	5	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	15	30	
Rise Time ^c	t _r	$V_{DD} = 75 \text{ V}, R_L = 1.25 \Omega$	-	114	220	ns
Turn-Off Delay Time °	t _{d(off)}	$I_D \cong 30 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	28	56	
Fall Time ^c	t _f		-	8	16	
Drain-Source Body Diode Ratings ar	nd Characteri	stics ^b (T _C = 25 °C)				
Pulsed Current (t = 100 μs)	I _{SM}		-	-	330	Α
Forward Voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V	-	0.73	1.2	V
Reverse Recovery Time	t _{rr}		-	110	220	ns
Peak Reverse Recovery Charge	I _{RM(REC)}	$I_F = 10 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	10	20	Α
Reverse Recovery Charge	Q _{rr}		-	0.5	1	μC

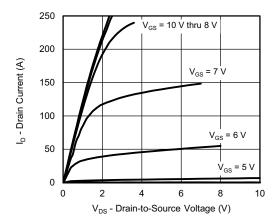
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

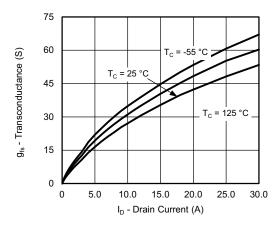
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



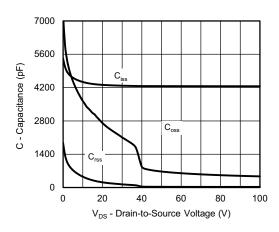
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



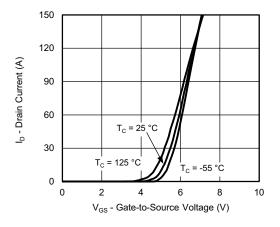
Output Characteristics



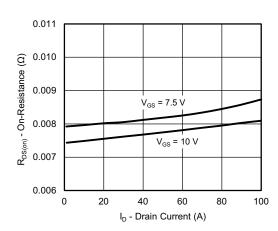
Transconductance



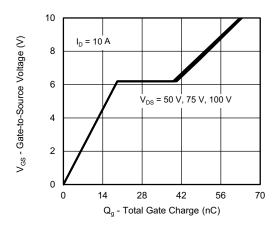
Capacitance



Transfer Characteristics



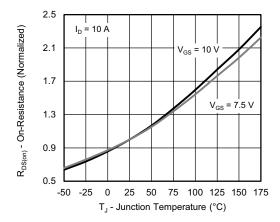
On-Resistance vs. Drain Current



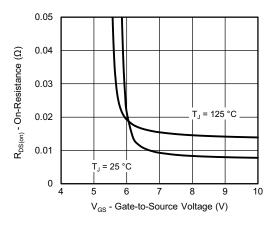
Gate Charge



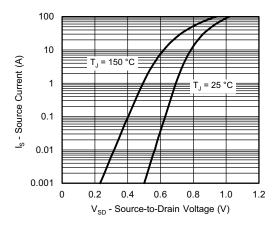
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



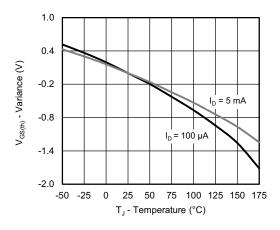
On-Resistance vs. Junction Temperature



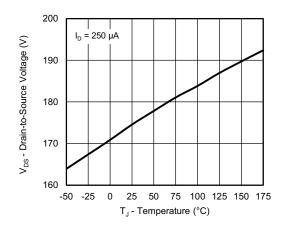
On-Resistance vs. Gate-to-Source Voltage



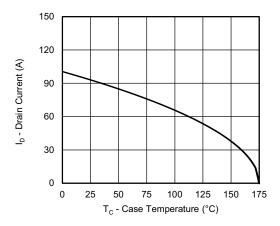
Source Drain Diode Forward Voltage



Threshold Voltage



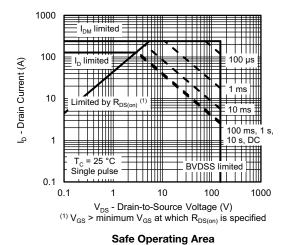
Drain Source Breakdown vs. Junction Temperature

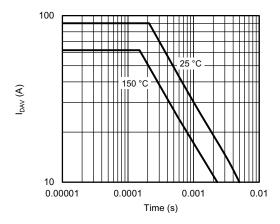


Current De-Rating

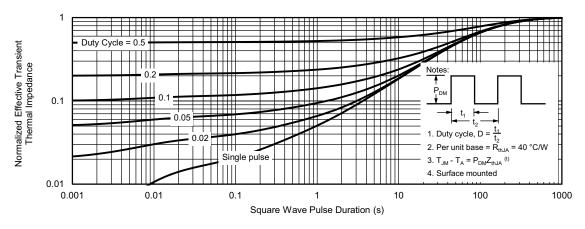


THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)





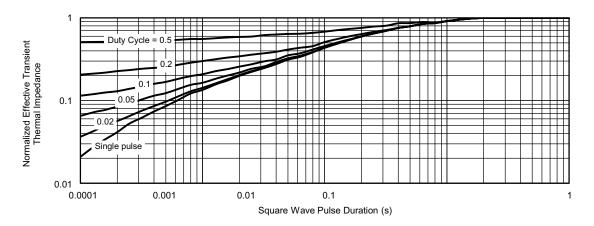
 I_{DAV} vs. Time



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

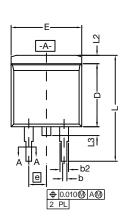
Note

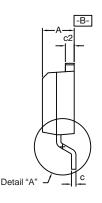
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C)

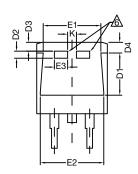
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.



TO-263 (D²PAK): 3-LEAD

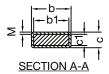








DETAIL A (ROTATED 90°)



		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
A		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
. +	Thin lead	0.013	0.018	0.330	0.457	
C*	Thick lead	0.023	0.028	0.584	0.711	
	Thin lead	0.013	0.017	0.330	0.431	
c1	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
D1		0.220	0.240	5.588	6.096	
D2		0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	E	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017 9.52		
	E3	0.072	0.078	1.829	1.981	
e		0.100 BSC		2.54 BSC		
	K	0.045	0.055	1.143	1.397	
L		0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
L4		0.010	BSC	0.254	0.254 BSC	
М		_	0.002	-	0.050	

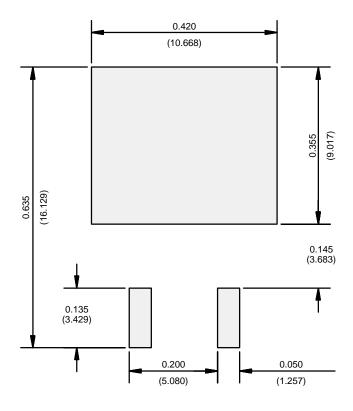
Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement. This feature is for thick lead.





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)





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